

# Effect of the inhomogeneity of substrate on wetting transitions

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## Abstract

We study the substrate inhomogeneity effect on the wetting of a spin-1/2 Ising ferromagnetic film in an external magnetic field  $H$ , using Monte Carlo simulations. It is found that the inhomogeneity leads to the formation of clusters of positive and negative spins in each layer. However, depending on the values of  $H$ , for a fixed surface magnetic field  $H_s$ , each layer exhibits three different phases; totally wet, no wet and partially wet. In the latter case, we show the existence of three distinct configurations namely: A configuration in which the layer is partially wet with a total disconnection between clusters (PWTD); a configuration in which the layer is partially wet with a partial disconnection between clusters (PWPD); the configuration in which the layer is partially wet and the clusters are totally connected (PWTC). Furthermore, we show that an increase of  $H_s$  values breaks the bonds connecting some clusters of the phase (PWTC) which leads to an expansion of the (PWPD) region. On the other hand, the frequency distribution and the average size of clusters are investigated in the (PWTD) region for fixed values of temperature  $T$ ,  $H_s$  and  $H$ . Moreover, we show the existence of 3D-islands resulting from the formation of islands in each layer.

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Keywords: Wetting; Monte Carlo simulations; Inhomogeneity; Layering; island distribution.

## 1 Introduction

Multilayers adsorbed on attractive substrates may exhibit a variety of possible phase transitions, as has been reviewed by Pandit et al. [1], Pandit and Wortis [2], Ebner et al. [3] and Patrykiewicz et al. [4]. The existence of phase diagrams depending on the strength of the substrate potential in a lattice gas model for multilayer adsorption, have been shown by Benyoussef and Ez-Zahraoui [5]. The wetting and layering transitions are caused by the competition between short-ranged attractions and long-ranged repulsions in systems like Langmuir monolayers and adsorbed monolayers [6]. These transitions have also been found, under the effect of the geometry of the system, in the case of the double wedge wetting [7] in magnetic films, and the wetting behavior of associating binary mixtures at attractive walls [8]. We showed recently, in Ref. [9], the existence of these transitions under the effect of the surface coupling, when using the mean field theory.

On the other hand, many recent studies showed that indirect interactions can lead to the formation of nano-structures at surfaces [10] mediated by the structure and the geometry of the film. Monte Carlo Simulations [11] and subsequently derived mean field theories [12], showed the existence of higher island densities than those expected by standard nucleation theory. It is shown that several experimental works, e.g. [13], supports these predictions, such as the deposition of Au on mica substrates at a high temperature [14].

A small variation of the preparation conditions may considerably change the obtained magnetic structure and allows the investigation of atomic structure as well as the magnetic domain structure of several nanostructured systems [15,16]. However, Lenz and Lipowski [17] showed that the morphology of wetting layers on structured surfaces is determined by the geometry of the underlying surface domains, and that the wetting layer exhibits several distinct morphologies. On the other hand, it has been shown [18] in the case of a two-dimensional lattice-gas model, that some basic regimes of drying mediated nanoparticle assembly are distinguished by the spatial uniformity of solvent dynamics, and by the fluctuations of nanoparticle domain

boundaries following evaporation. It has also shown that when solvent disappears homogeneously from the surface, disk-like or ribbon-like domains reminiscent of spinodal decomposition form at early time. If instead domain boundaries are frozen following evaporation, dynamical constraints arrest this growth at an early stage. Network structures are formed as vapour nucleate [18], otherwise networks fragment to form distinct domain that asymmetrically evolve as in homogeneous coarsening.

Our aim in this work is to study the effect of the inhomogeneity of substrate on the wetting transitions of a spin-1/2 Ising film when a surface magnetic field is applied on alternate clusters of the surface. The paper is organized as follows. In section 2, we describe the model and the method used: Monte Carlo (MC) simulations. In section 3 we present results and discussions.

## 2 Model and Monte Carlo simulations

Our model can describe either a magnetic system in which the Ising spin variables are  $S_i = \pm 1$ , or a physical state of the liquid-gas model where the occupation variables  $n_i = \pm 1$ ; 0 (+1 when the site is occupied and 0 if the site is not occupied) can replace the spin variables when  $n_i = (1 + S_i)/2$ . The external magnetic field  $H$  and the surface magnetic field  $H_s$  can then play the role of the chemical potential and the substrate potential, respectively. These analogies concerning the lattice gas model and a magnetic system are more explained in Refs. [1-4]. The case a two-dimensional lattice gas model is studied in details in [18].

The system we are studying, illustrated by Fig. 1, is a magnetic thin film formed with  $N = 4$  layers coupled ferromagnetically. Each layer is a square of dimension  $N_x \times N_y = 64 \times 64$  spins.  $N_x$  and  $N_y$  stand for the number of spins in the  $x$  and  $y$  directions, respectively. A surface magnetic field  $H_s$  is acting only on alternate clusters of spins of the surface  $k = 1$ . This is represented, in Fig. 1, by symbols (+) for alternate clusters of dimension  $l_p \times l_p = 8 \times 8$ . Whereas  $H_s$  is absent for the remaining alternate clusters of dimension  $l_n \times l_n = 8 \times 8$ . These clusters are represented by symbols (o).

The Hamiltonian governing this system is given by

$$H = \sum_{\langle i,j \rangle} J_{ij} S_i S_j + \sum_i (H + H_{s_i}) S_i \quad (1)$$

where,  $S_i(l=i;j) = \pm 1$  are the random spin variables and

the interaction  $J_{ij}$  between different spins is assumed to be constant  $J_{ij} = J$ .

The first summation in Eq. (1) includes only the nearest neighbor spins. The second summation runs over all sites  $i$  of the system.  $H$  is an external magnetic field applied on each site of the film.

The surface magnetic field  $H_{s_i}$ , appearing in the Hamiltonian (1), is applied only on sites  $i$  of the surface  $k = 1$ , and distributed alternatively, according to:

$$H_{s_i} = \begin{cases} +H_s & \text{for all sites } i \text{ clusters with symbols (+)} \\ 0 & \text{for all sites } i \text{ clusters with symbols (o)} \end{cases} \quad (2)$$

The inhomogeneity in the surface results from this distribution of the magnetic field  $H_{s_i}$ .

We use the Monte Carlo simulations under the Metropolis algorithm.

An attempt to flip a randomly chosen spin in site  $i^0$  from up to down, or vice versa, is envisaged using the Metropolis probability:

$$p_M = \min[1; \exp(-E/k_B T)]; \quad (3)$$

where,  $E$  is the resulting change in energy after the flip of the spin  $i^0$ ,  $k_B$  is

the Boltzmann constant and  $T$  the absolute temperature. The flip of the spin is accepted if  $p_M$  is greater than a random number  $p_r$  generated by the computer so that  $p_r \in [0;1]$ .

Otherwise the flip of the spin located at the site ' $i$ ' is ignored if the randomly generated number is so that  $p_r > p_M$ . One Monte Carlo step (MCS) is reached once the number of visited sites is close to the number of sites of the system. For a fixed temperature and/or surface magnetic field, runs of  $5 \times 10^6$  Monte Carlo steps (MCS) are performed for different initial conditions. Mean values of computed quantities are estimated for different initial conditions, with the discard of the first  $5 \times 10^5$  (MCS) for each run.

A preliminary study showed that the topologies of the phase diagrams are similar (with different numerical values) when the film thickness varies from  $N = 3$  to  $N = 9$  layers, when the number of spins of each layer varies from  $N_x = N_y = 16$  to  $N_x = N_y = 64$ ; where  $N_x$  and  $N_y$  are the number, of spins of each layer, in the  $x$  and  $y$  directions, respectively. When increasing the film thickness, the topology of the established phase diagrams are similar for thin films ( $N < 10$ ) layers. For simplicity and fast Monte Carlo simulations, and taking into account the above considerations we give numerical results in this paper for a film

with  $N = 4$  layers and  $N_x = N_y = 64$  spins for each layer.

We mean by an 'island', a set of negative spins surrounded by positive ones. In all the following, our interest will be concentrated on the mean size of islands ( $\overline{MSI}$ ) and the average number of islands ( $\overline{ANI}$ ). The different phases are determined by values of the average number of islands and their mean sizes as following:

The PWTD phase is characterized by:  $\overline{ANI} = 32$  and  $\overline{MSI} = (N_x + N_y)/2$ .

The PWPD phase is present for:  $\overline{ANI} = 32$  and  $(N_x + N_y) = 2 \times \overline{MSI}$ .

The PWTC phase corresponds to:  $\overline{ANI} = 1$  and  $\overline{MSI} = (N_x + N_y)/2$ .

However, in the particular case of the non wet phase, we have  $\overline{ANI} = 1$  and  $\overline{MSI} = N_x + N_y$  (which is the total number of spins of each layer). We note that in this particular case, although positive spins are completely absent in the layer, we assume that this situation corresponds to a unique island.

### 3 Results and discussion

A sketch of the geometry of the system we are studying, is presented in Fig. 1. In order to outline the behaviour of the mean size of islands ( $\overline{MSI}$ ) and the average number of islands ( $\overline{ANI}$ ) as a function of the external magnetic field, we plot in Figs. 2a and 2b, these parameters, for a surface magnetic field  $H_s = 2.5$  and a temperature  $T = 3.5$ . Indeed, Fig. 2a corresponds to the surface  $k = 1$ , whereas Fig. 2b is plotted for the last layer  $k = N = 4$ . It is found that, for the surface  $k = 1$  (Fig. 2a) and the last layer  $k = N$  (Fig. 2b), when decreasing the external magnetic field from  $H = 0$ , the average number of islands ( $\overline{ANI}$ ) exhibits two islands for  $H < 0.1$ , with a rapid increasing of the number of negative spins in each layer, as it is illustrated by the mean size of islands ( $\overline{MSI}$ ) curve. For  $T = 3.5$  and  $0.16 < H < 0.07$ , the average number of islands ( $\overline{ANI}$ ) increases rapidly and the mean size of islands ( $\overline{MSI}$ ) undergoes a local maximum. When decreasing the magnetic field  $H$  so that  $H < 0.20$  the average number of islands of the surface stabilizes at 32, whereas it drops suddenly to one cluster formed with negative spins, in the case of the last layer  $k = N$ . In the case of the surface, the mean size of islands ( $\overline{MSI}$ ) undergoes a large local plateau corresponding to the value 64, followed by the apparition of a unique island for  $H < 0.80$ . This scenario is absent in the case of the last layer  $k = N$ , Fig. 2b, where the islands are rapidly connected to

each other for  $H < 0.15$ . On the other hand, the increasing surface magnetic field effect, on island formation is illustrated by Figs. 3a and 3b for a fixed temperature  $T = 3.5$  for several values of the surface magnetic field:  $H_s = 1.5$ ,  $H_s = 2.0$  and  $H_s = 2.5$ . Indeed, for small values of the external magnetic field,  $0.20 < H < 0$ , the increasing surface magnetic field  $H_s$  is not felt at this "higher" temperature value 3.5. While, for  $H < 0.20$ , the increasing surface magnetic field amplitude is to produce a large step of mean size island value 64, see Fig. 3a. It is worth to note that this step disappears for very small surface magnetic field values. Concerning the average number islands (ANI), the same arguments still valid when increasing the surface magnetic field amplitude  $H_s$ , Fig. 3b. The islands are rapidly connected to each other for very small values of  $H_s$ . On the other hand, we show in Fig. 4 the existence of three regions of island configurations in the plane  $(T; H)$ , for  $k = N$  and a fixed surface magnetic field  $H_s = 2.0$ . These three different regions are: the totally wet (TW) region, the non wet region (NW) and the partially wet region. In the latter case, see in Fig. 4, the existence of three distinct island configurations, namely; the (PWTD) configurations where the layer is partially wet with a total disconnection of the islands; the (PWPD) configurations in which the layer is partially wet with a partial disconnection of the islands; The (PWTC) configurations corresponding to a partially wet layer with totally connected clusters. Indeed, at low temperature values, only the totally wet (TW) phase for  $H = 0$ , and the non wet (NW) phase for  $H = 0.5$  are present. At higher temperature values, provided that  $T$  is kept less than the critical value  $T_c = 3.87$ , the partially wet phase occurs. Starting from the totally wet phase (TW), present for positive values of  $H$ , the decreasing of the external magnetic field (from 0 to negative values), gives rise to the phase (PWTD) showing totally disconnected configuration of islands. This phase is followed by the (PWPD) phase in which the configuration of islands are partially disconnected when  $0.16 < H < 0.07$ . For  $H = 0.20$ , the partially wet phase (PWTC) where the islands are totally connected to each other, is reached. Decreasing the magnetic field  $H$  more and more, the non wet phase (NW) is found and persists for  $H \leq -1$ . The topology of the established phase diagrams stand valid for the other layers  $k < N$  of the  $\text{Im}$ . The layer  $k=4$  is chosen because the studied phases in the partially wetting region: totally disconnected (PWTD), partially disconnected (PWPD), and totally connected (PWTC) are well outlined in this layer. Moreover this layer is chosen in order to outline the range effect of the substrate on deeper layers.

In order to more clarify these findings, we plot in Figs. 5a and 5b, different island configurations in different regions of the phase diagram for the different layers of the film.

Indeed, Fig. 5a, shows that, for  $H_s = 2.0$ ,  $T = 3.5$  and  $H = 0.13$ , the first layer  $k = 1$  shows a configuration corresponding to a partially wet layer with totally connected clusters (PW TC). The second layer  $k = 2$  belongs to the partially disconnected configuration (PW PD), whereas the third layer  $k = 3$  is in the totally disconnected phase (PW TD). On the other hand, when maintaining the parameters  $T$  and  $H_s$  constant, and varying only the external magnetic field, a given layer undergoes different configurations belonging to different regions: totally connected (PW TC), partially disconnected (PW PD) and totally disconnected (PW TD). This situation is illustrated by Fig. 5b for the last layer  $k = 4$ . Indeed, for  $H = 0.13$  this layer is in the totally connected phase (PW TC). For  $H = 0.15$  the configuration of this layer partially disconnected (PW PD); and when  $H = 0.17$  the islands of this layers are completely disconnected from each other so that this configuration belongs to totally disconnected (PW TD) region. The numerical values given in this work correspond to  $N_x = N_y = 64$ . However, a preliminary study showed that when  $N_x = N_y = 32$  and  $T = 3.5$  the partially disconnected region (PW PD) is located in the interval  $0.13 < H < 0.09$ . Hence, the finite size effect and thermodynamic limit is to enlarge partially wetting regions (PW). Moreover, the formation of islands in each layer leads to the formation of the three dimensional islands (3D-islands). The superposition of these 2D-island of adjacent layers leads to the formation of such 3D-islands in the film. For example, Fig. 5a shows these 3D-islands, when superposing the layers  $k = 1; 2; 3$  over each other. This situation is more outlined, for example, in the rectangle of coordinates in the rectangle  $16 \times 24$  and  $32 \times 40$  for the layers  $k = 1; 2; 3$  and 4, respectively. The superposition of these islands constitute a three dimensional island in the bulk of the film. However, the height of the formed islands depends on the values of temperature, surface and external magnetic fields. In the example of Fig. 5a, some island heights are close to 4. A preliminary study showed that the island height decreases with decreasing values of  $H_s$ , for fixed values of temperature  $T$  and external magnetic field  $H$ . To complete this study, the frequency distribution of different configurations, are plotted in Fig. 6. This figure shows the corresponding frequency island size distributions, for the totally disconnected region (PW TD), for the layers  $k = 1$ ,  $k = 2$ ,  $k = 3$  and  $k = 4$  when the temperature is fixed at  $T = 3.5$ , the surface magnetic field is  $H_s = 2.0$  and  $H = 0.142$ . The different scenarios presented by

the system concerning the inhomogeneity substrate effect on the distribution of cluster sizes and number of existing clusters are presented. Indeed, the mean size cluster of negative spins undergoes a local maximum before exhibiting first and second steps. The plateau of the first step increases with increasing surface magnetic field values.

## 4 Conclusion

We have studied the effect of the inhomogeneity of a substrate on the wetting transitions of a spin-1=2 ferromagnetic Ising thin film under the effect of an alternate surface magnetic field  $H_s$  acting on alternate clusters of the surface, using Monte Carlo simulations. In the partial wetting region each layer exhibits three different configurations namely: partial wetting with totally disconnected cluster (PW TD), partial wetting with partially disconnected clusters (PW PD) and partial wetting with totally connected clusters (PW TC). On the other hand, we found that increasing the surface magnetic field leads to the disconnection of some connected clusters in the (PW PD) region. Furthermore the 3D-islands occur for strong surface magnetic field values. Moreover, the distributions of the cluster size, in each layer of the film, are also computed.

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## Figure Captions

### Figure 1.:

A geometry sketch of the studied system formed with  $N = 4$  layers. A surface magnetic field  $H_s$  is acting on alternate cluster spins of the surface  $k = 1$ .  $H_s$  is present on islands with symbols:  $\uparrow\downarrow$ , and absent elsewhere: islands with symbols  $\uparrow\uparrow$ .

### Figure 2:

The dependency of the mean size of islands ( $\langle MSI \rangle$ ), and the average number of islands ( $\langle ANI \rangle$ ) of the surface  $k = 1$  (a), and the last layer  $k = N$ , as a function of the external magnetic field  $H$  for a fixed temperature  $T = 3.5$  and a surface magnetic field value  $H_s = 2.5$ .

Figure 3:

(a) The mean size of islands ( $\langle M_{SI} \rangle$ ), and (b) the average number of islands ( $\langle N_I \rangle$ ) of the surface  $k = 1$  as a function of  $H$  for  $T = 3.5$  and several values of  $H_s$ : 1.5; 2.0 2.5.

Figure 4:

The  $(T; H)$  phase diagram for the layer  $k = 4$ , as a function of the external magnetic field  $H$ , for several values of the surface magnetic field  $H_s$ : 1.5; 2.0 and 2.5. The regions corresponding to the different configurations: (TW) totally wet, (PW TC) partially wet with totally connected clusters, (PW PD) partially wet with partially disconnected clusters, (PW TD) partially wet with totally disconnected clusters, and (NW) non wet, are presented.

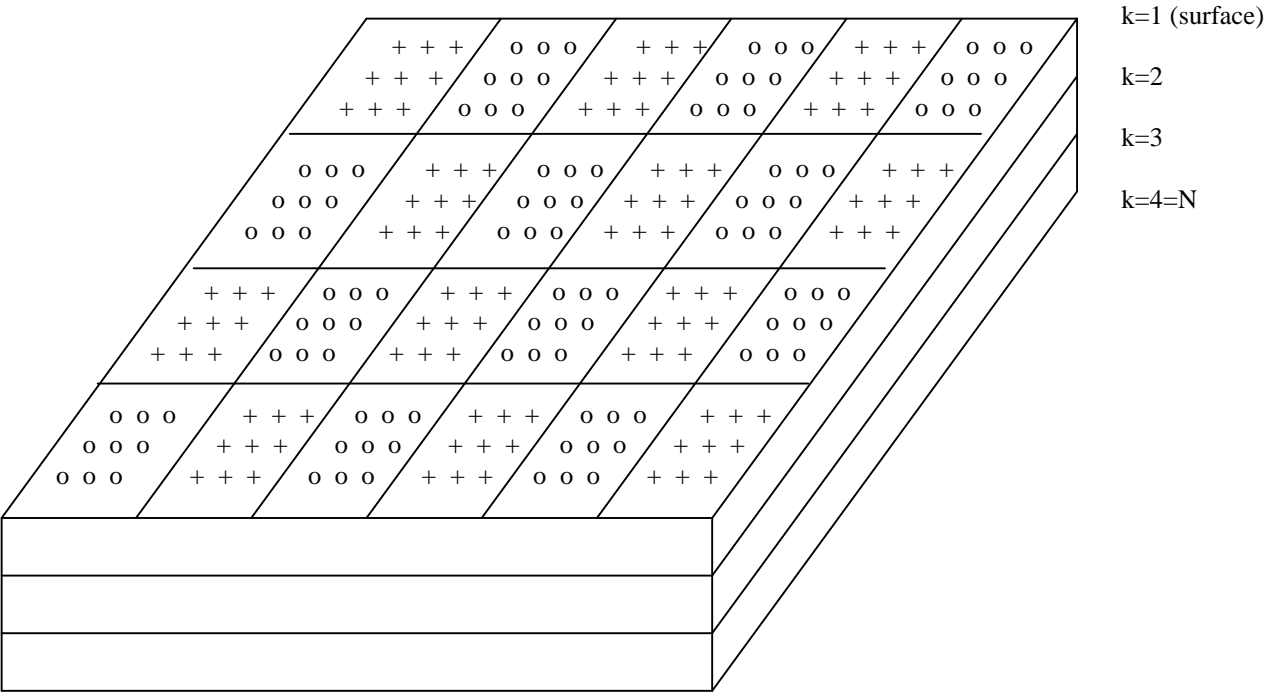
Figure 5:

island maps of positive spins for different layers of the film with  $N = 4$  a) The first layer  $k = 1$  is in the (PW TC) configuration, the second layer  $k = 2$  is in the configuration (PW PD), while the layer  $k = 3$  belongs to the configuration (PW TD); for  $T = 3.5$ ,  $H = 0.13$  and  $H_s = 2.0$ . b) For  $H = 0.13$ ,  $H = 0.15$  and  $H = 0.17$ , the last layer  $k = 4$  exhibits three different configurations (PW TC), (PW TD) and (PW TD), respectively, for  $T = 3.7$  and  $H_s = 2.0$ .

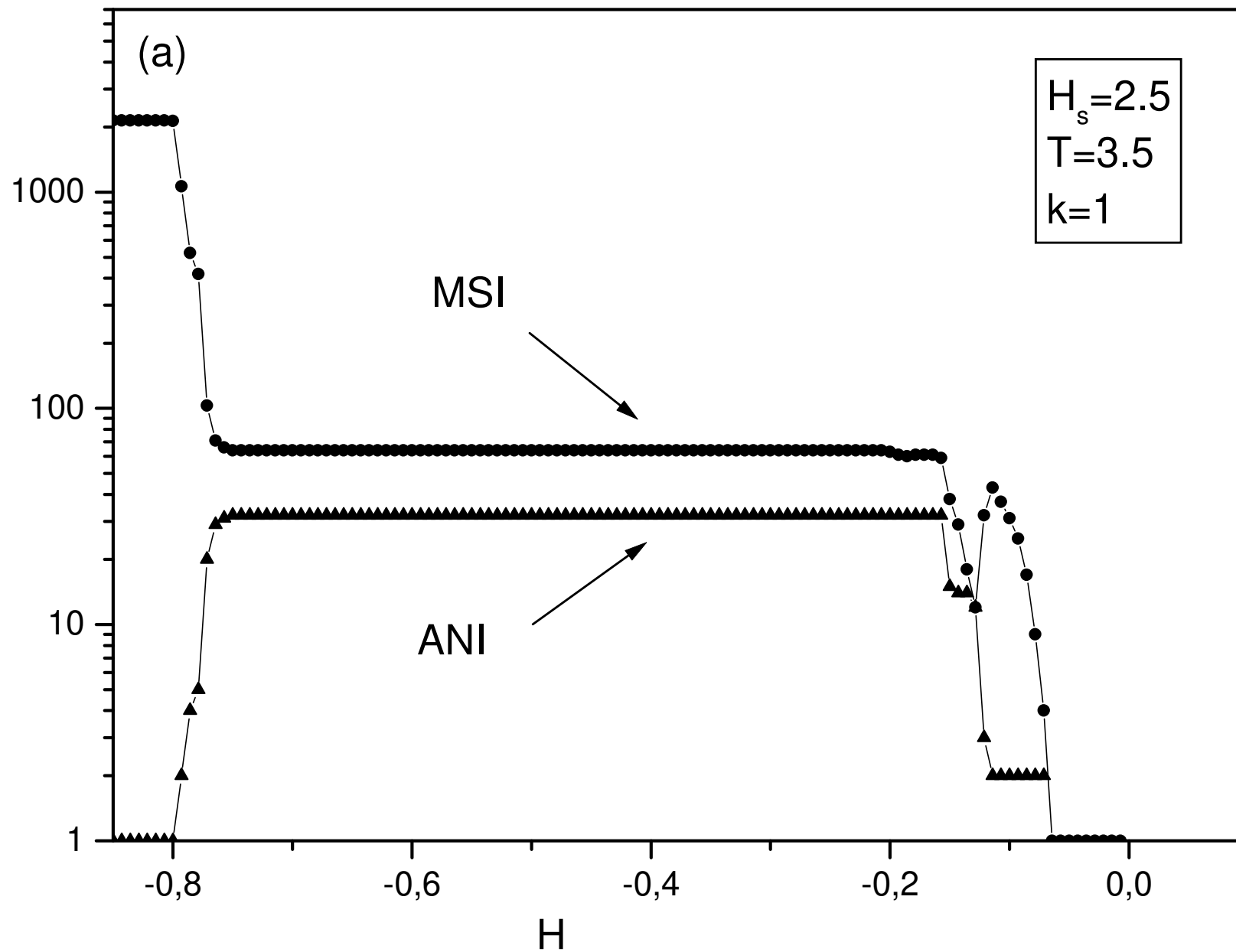
Figure 6:

Frequency island size distributions for the layers  $k = 1$ ,  $k = 2$ ,  $k = 3$  and  $k = 4$  for the configuration (PW TD) corresponding to  $T = 3.5$ ,  $H_s = 2.0$  and  $H = 0.142$ .

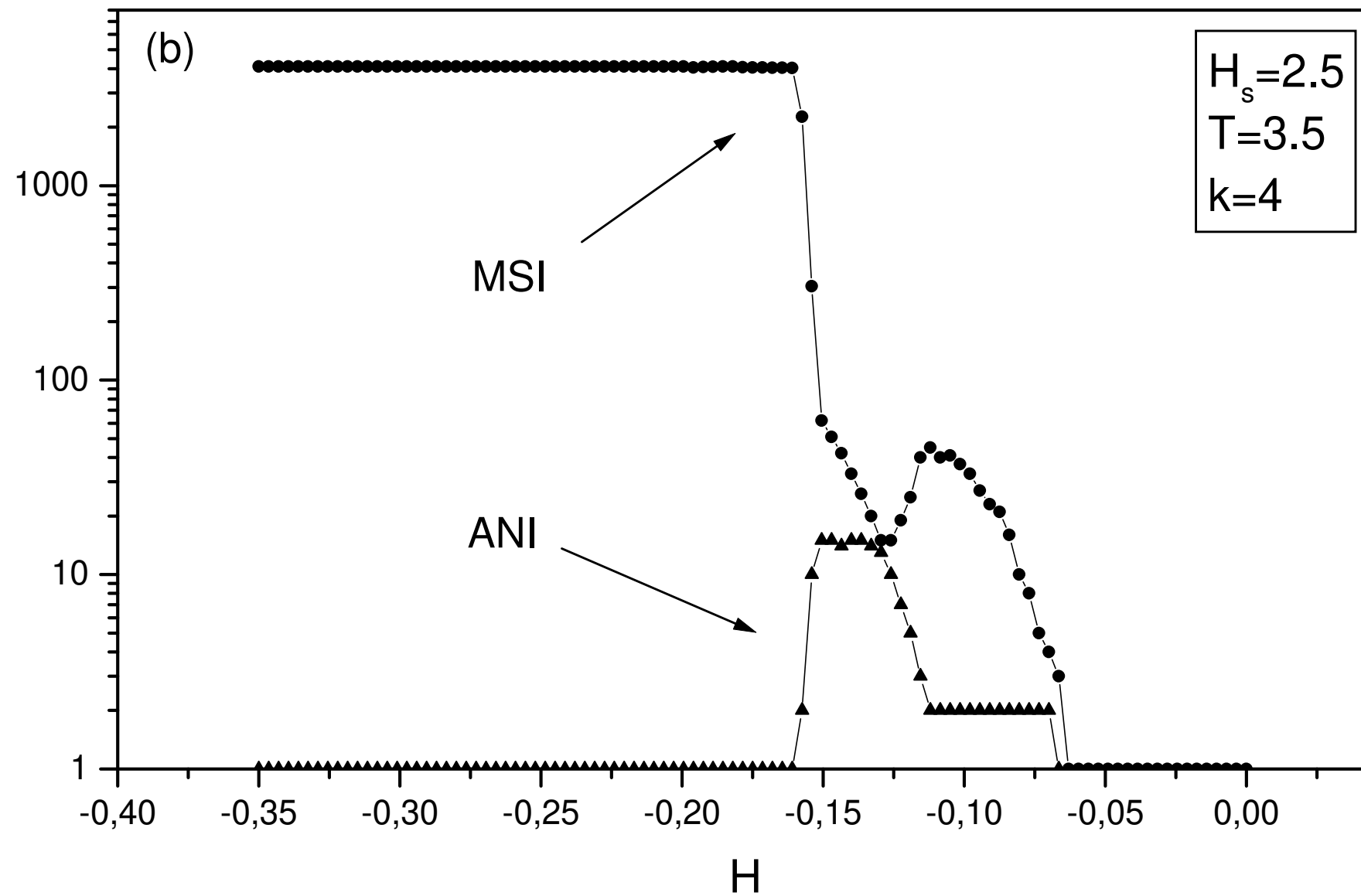
Fig. 1



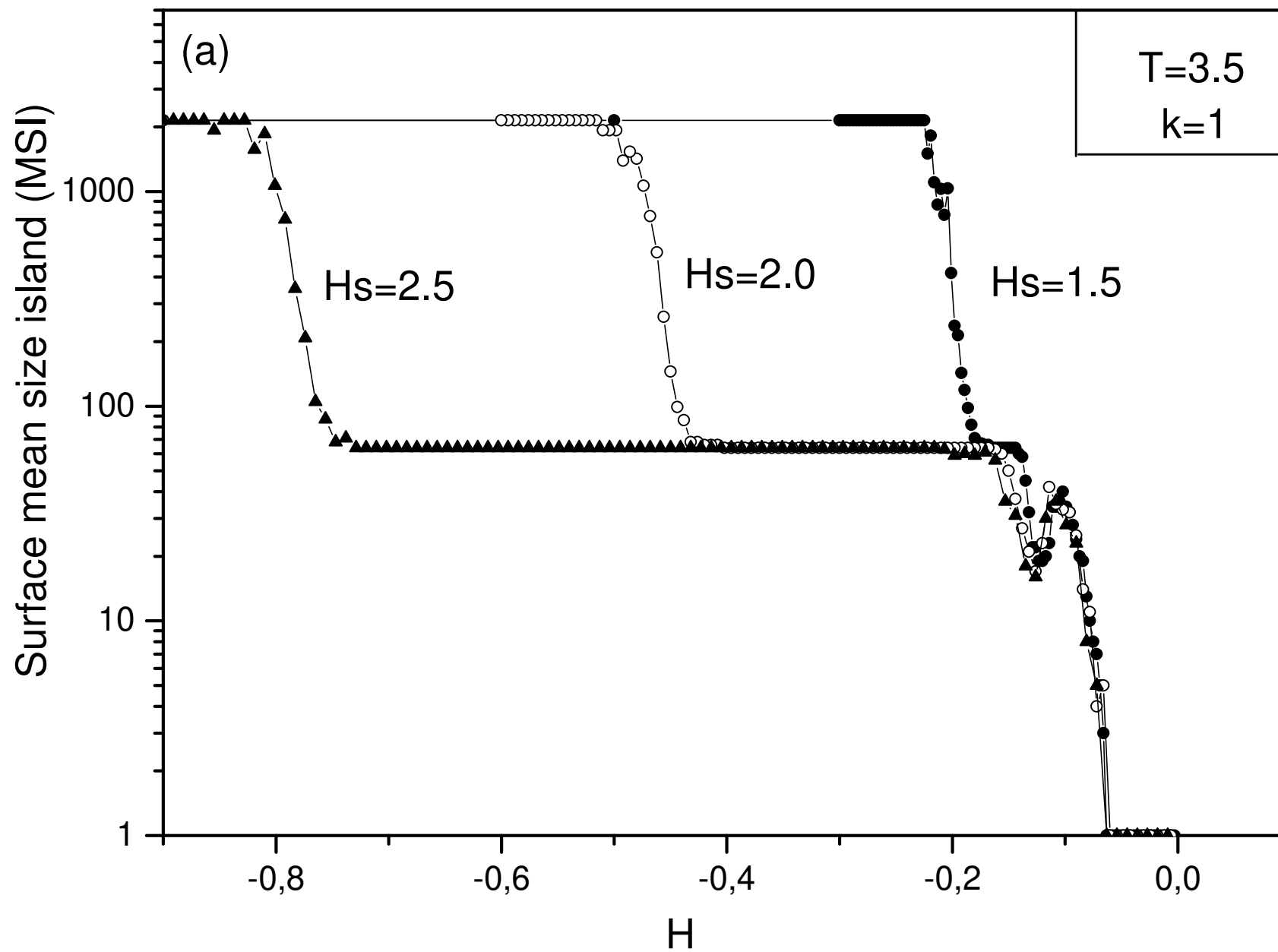














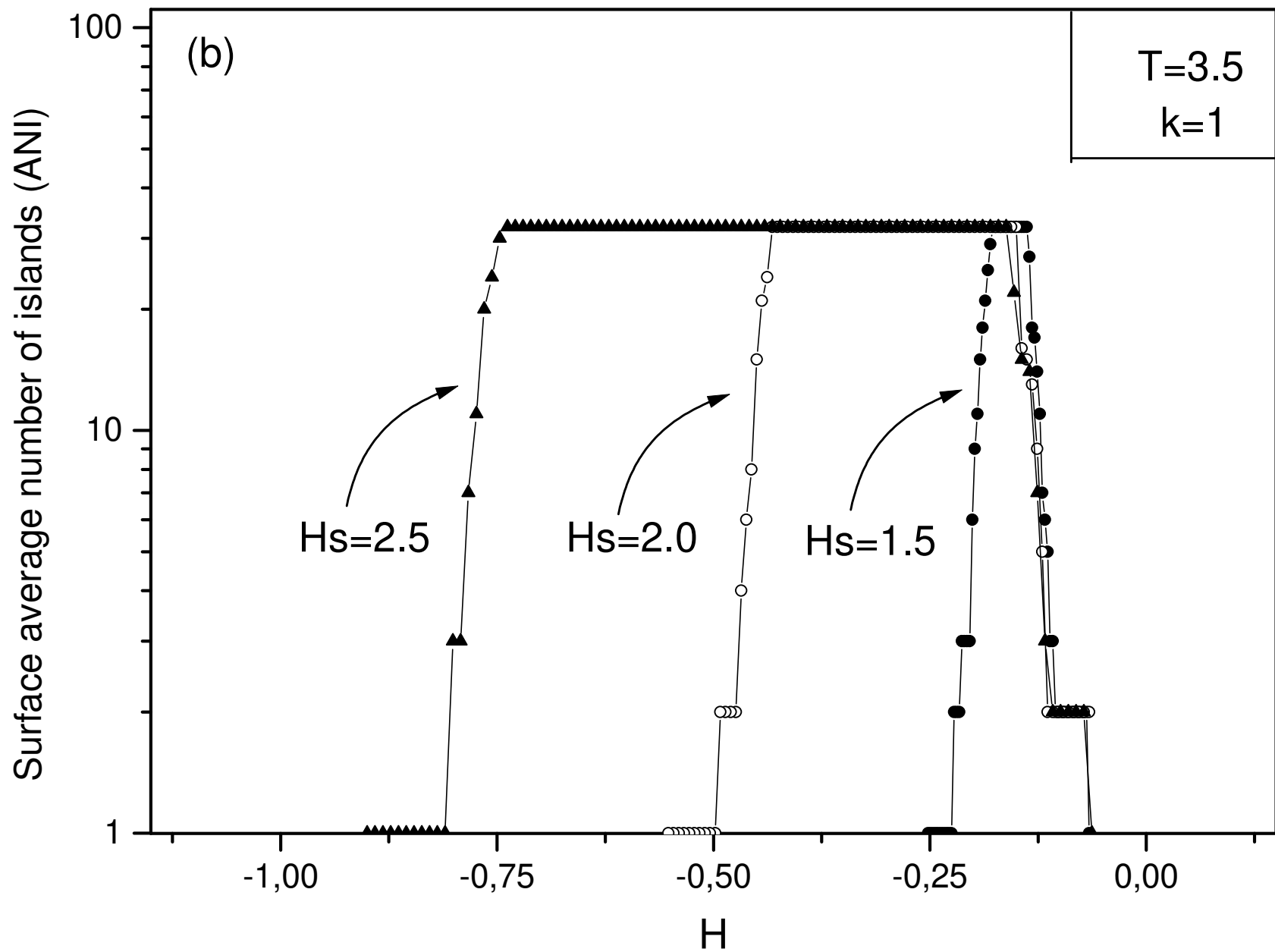
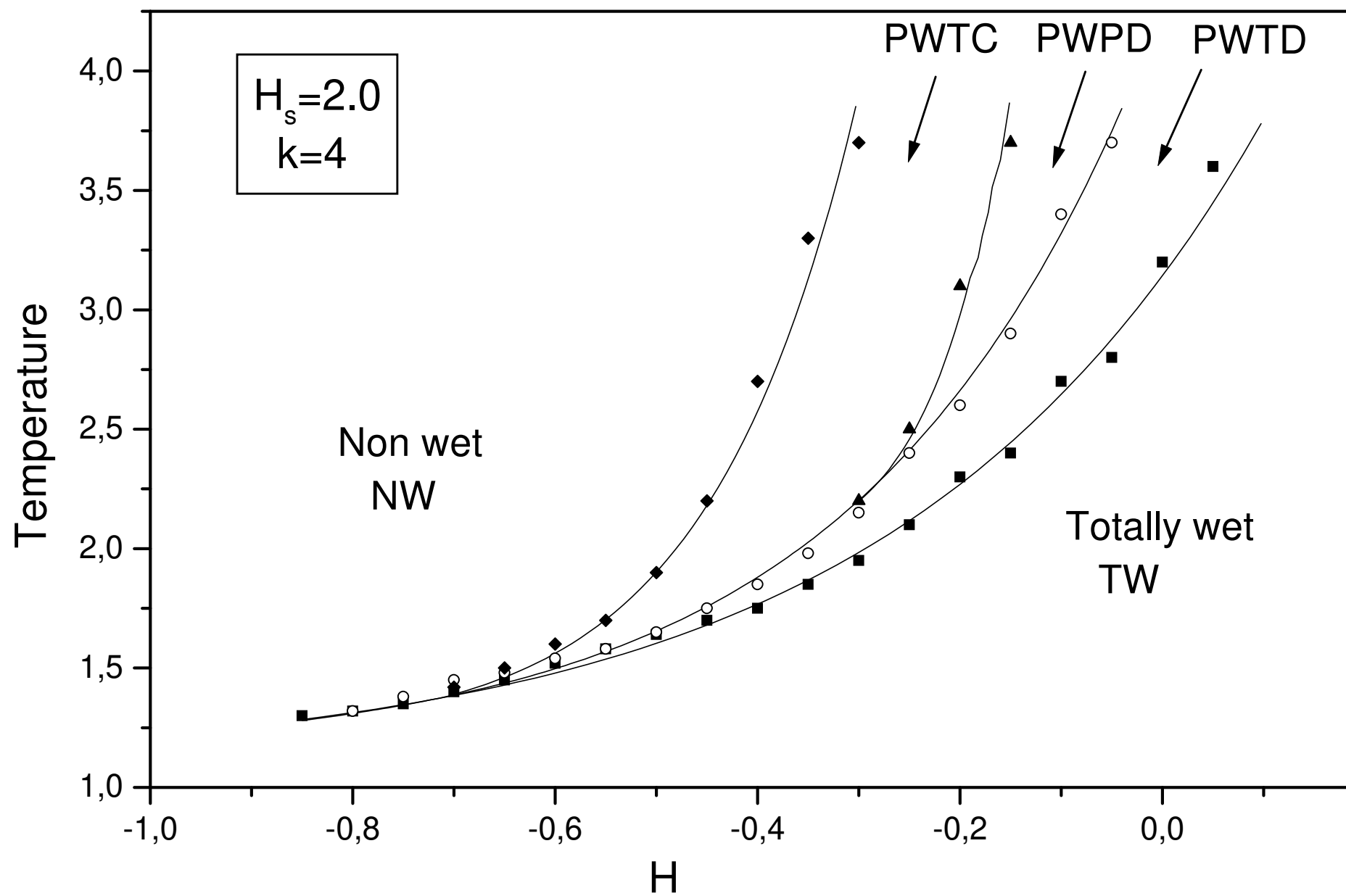


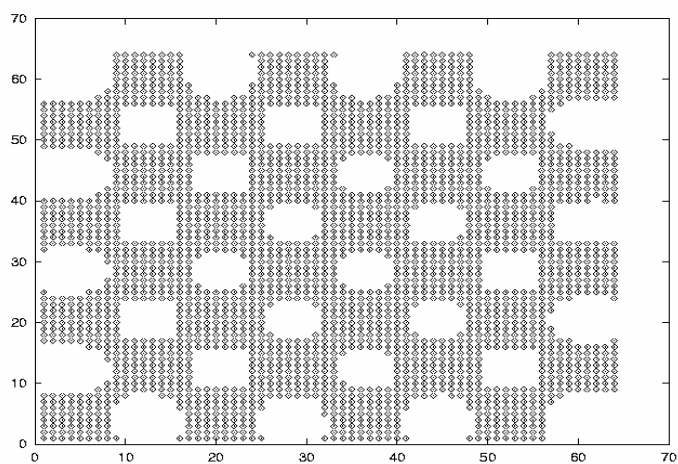


Fig. 4

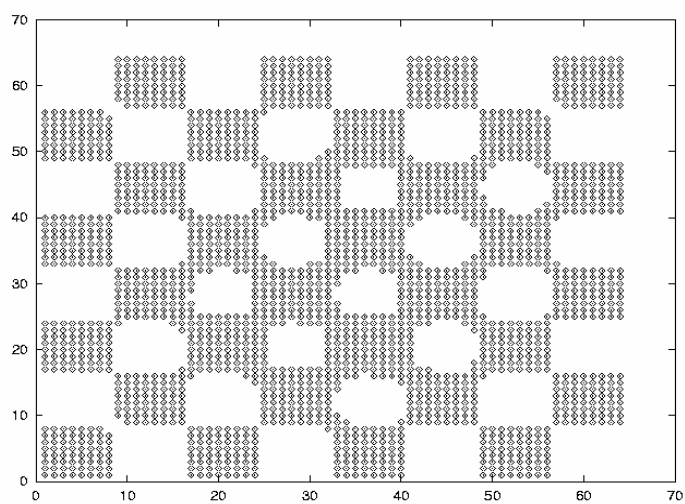




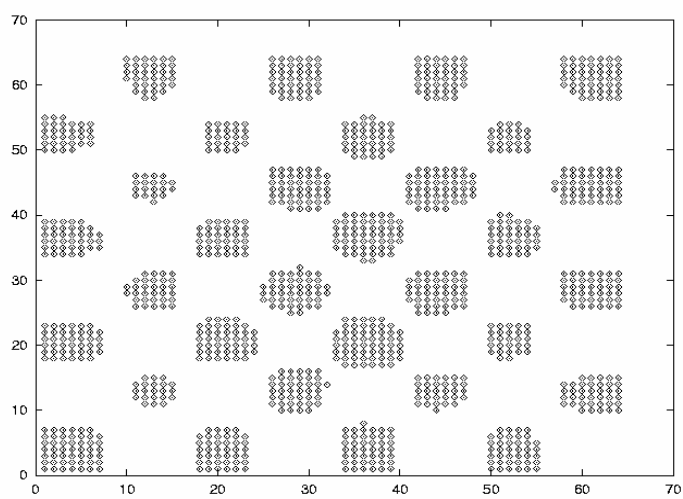
(a)



k=1  
PSTD



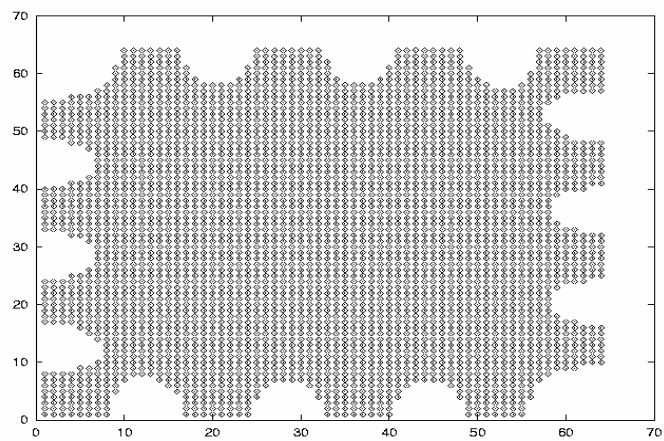
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PSTD



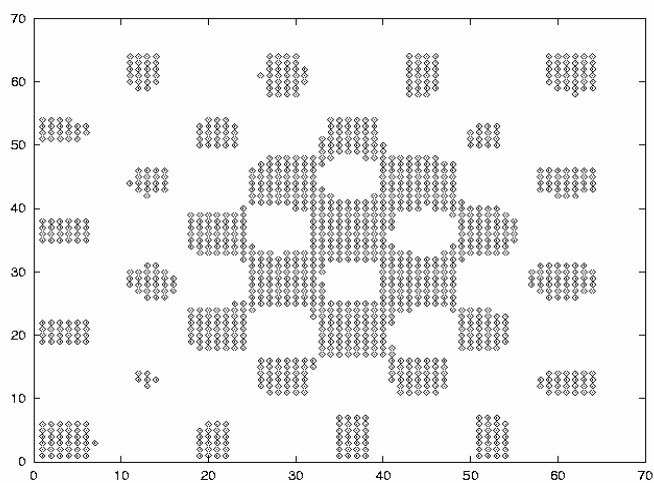
k=3  
PSTD



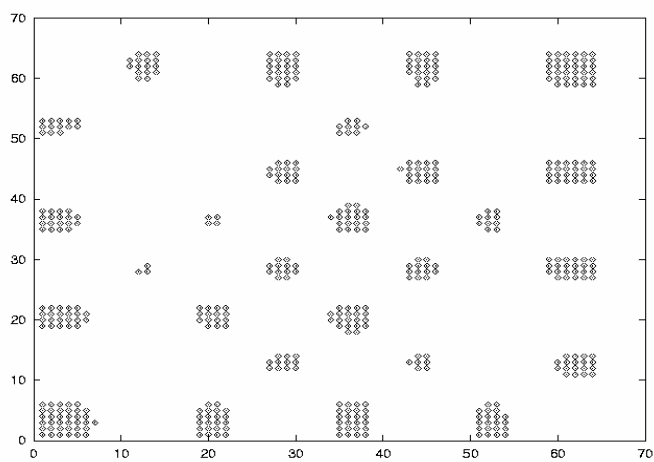
(b)



k=4  
PSTD



k=4  
PWD



k=4  
PWC



Fig. 6

